

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	646874	(light near emitting) LED	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/09 14:54
L2	489	((single mono) near3 (crystal\$6 polycrystal\$6) near4 (substrate wafer)) with (absor\$5 peak)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 14:55
L3	103	1 and 2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 14:55

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L17	165	((single mono) near3 (crystal\$6 polycrystal\$6) near4 (substrate wafer)) with (dislocation near5 density)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 10:13
L18	24836	GaN (Gallium near nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 10:14
L19	657468	(light near emitting) LED	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 10:14
L20	66	17 and 18 and 19	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/09 10:14